PMK35EP

P-channel TrenchMOS extremely low level FET

Rev. 02 — 29 April 2010 Product data sheet

1. Product profile

1.1 General description

Extremely low level P-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

1.2 Features and benefits

- Low conduction losses due to low on-state resistance

1.3 Applications

- Battery management
- Load switching

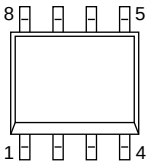
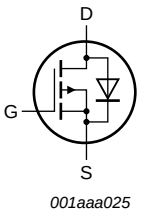
1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T_j ≤ 150 °C	-	-	-30	V
I_D	drain current	T_{sp} = 25 °C; V_{GS} = -10 V; see Figure 1; see Figure 3	-	-	-14.9	A
P_{tot}	total power dissipation	T_{sp} = 25 °C; see Figure 2	-	-	6.9	W
Static characteristics						
R_{DSon}	drain-source on-state resistance	V_{GS} = -10 V; I_D = -9.2 A; T_j = 25 °C; see Figure 9	-	16	19	mΩ
Dynamic characteristics						
Q_{GD}	gate-drain charge	V_{GS} = -10 V; I_D = -9.2 A; V_{DS} = -15 V; T_j = 25 °C; see Figure 11; see Figure 12	-	6	-	nC

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 SOT96-1 (SO8)	 001aaa025
2	S	source		
3	S	source		
4	G	gate		
5	D	drain		
6	D	drain		
7	D	drain		
8	D	drain		

3. Ordering information

Table 3. Ordering information

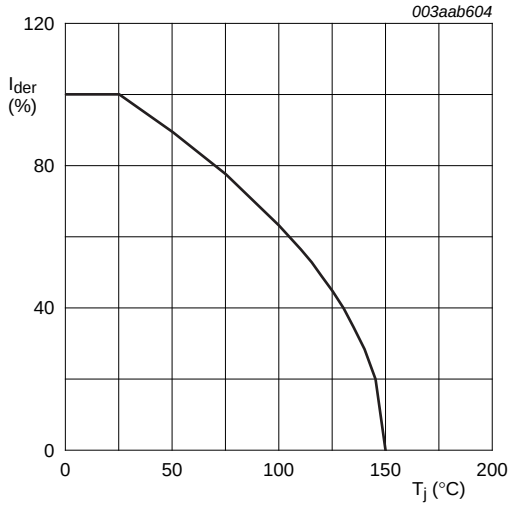
Type number	Package		
	Name	Description	Version
PMK35EP	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

4. Limiting values

Table 4. Limiting values

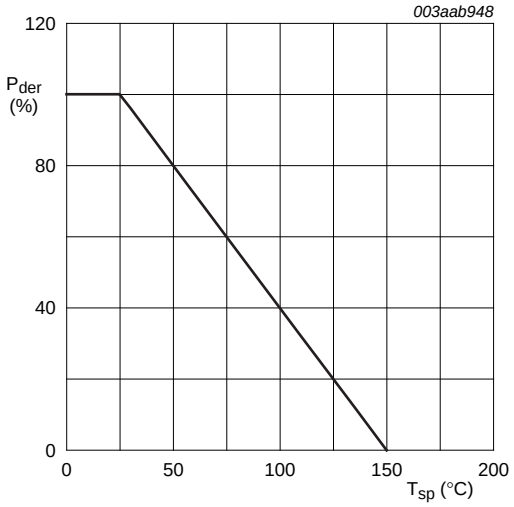
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T_j ≤ 150 °C	-	-	-30	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 150 °C; R_{GS} = 20 kΩ	-	-	-30	V
V_{GS}	gate-source voltage		-25	-	25	V
I_D	drain current	T_{sp} = 25 °C; V_{GS} = -10 V; see Figure 1; see Figure 3	-	-	-14.9	A
		T_{sp} = 100 °C; V_{GS} = -10 V; see Figure 1	-	-	-7	A
I_{DM}	peak drain current	T_{sp} = 25 °C; t_p ≤ 10 µs; pulsed; see Figure 3	-	-	-28.8	A
P_{tot}	total power dissipation	T_{sp} = 25 °C; see Figure 2	-	-	6.9	W
T_{stg}	storage temperature		-55	-	150	°C
T_j	junction temperature		-55	-	150	°C
Source-drain diode						
I_S	source current	T_{sp} = 25 °C	-	-	-5.8	A
I_{SM}	peak source current	T_{sp} = 25 °C; t_p ≤ 10 µs; pulsed	-	-	-23	A



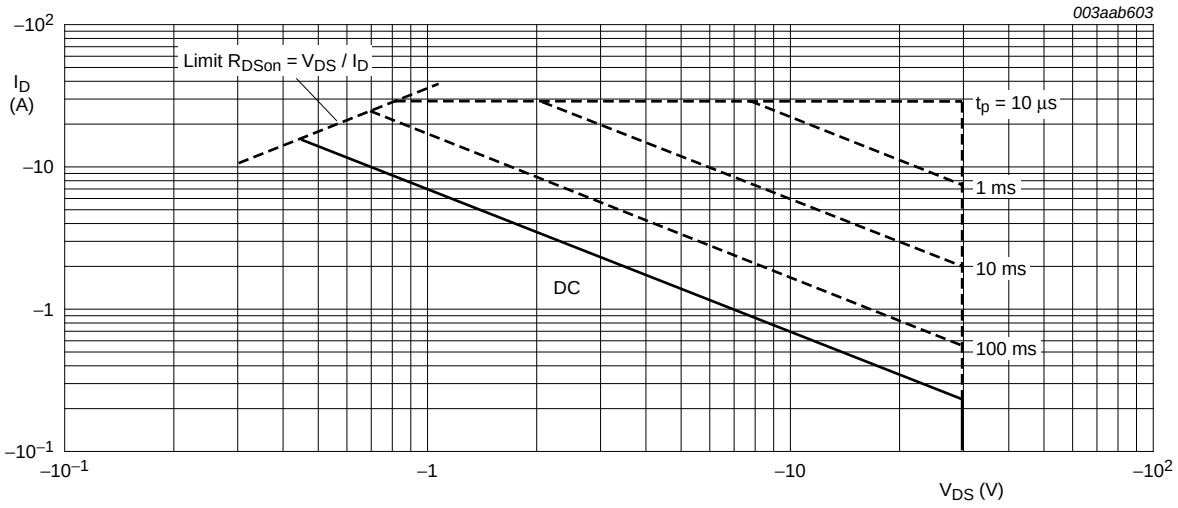
$$I_{der} = \frac{I_D}{I_{D(25°C)}} \times 100\ \%$$

Fig 1. Normalized continuous drain current as a function of solder point temperature



$$P_{der} = \frac{P_{tot}}{P_{tot(25°C)}} \times 100\ \%$$

Fig 2. Normalized total power dissipation as a function of solder point temperature



T_{sp} = 25 °C; I_{DM} is single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j\text{-}sp)}$	thermal resistance from junction to solder point	see Figure 4	-	-	18	K/W

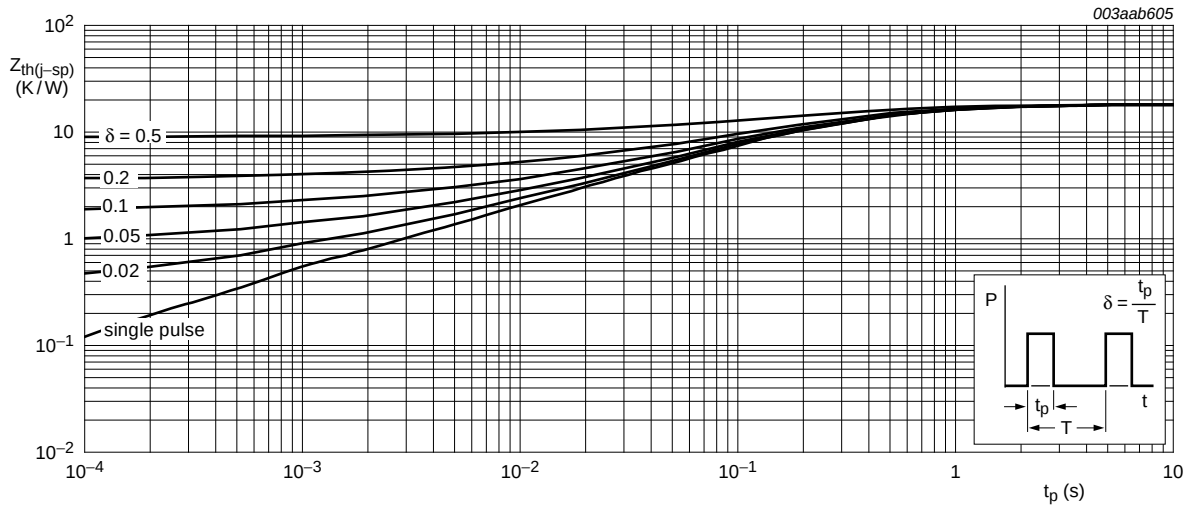


Fig 4. Transient thermal impedance from junction to solder point as a function of pulse duration

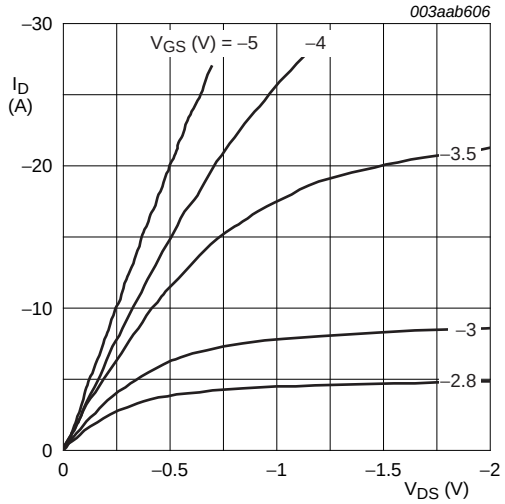
6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-30	-	-	V
		I_D = -250 µA; V_{GS} = 0 V; T_j = -55 °C	-27	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS}; T_j = 25 °C; see Figure 7; see Figure 8	-1	-	-3	V
		I_D = -250 µA; V_{DS} = V_{GS}; T_j = 150 °C; see Figure 7; see Figure 8	-0.7	-	-	V
		I_D = -250 µA; V_{DS} = V_{GS}; T_j = -55 °C; see Figure 7; see Figure 8	-	-	-3.3	V
I_{DSS}	drain leakage current	V_{DS} = -30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	µA
		V_{DS} = -30 V; V_{GS} = 0 V; T_j = 70 °C	-	-	-10	µA
I_{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = -10 V; I_D = -9.2 A; T_j = 25 °C; see Figure 9	-	16	19	mΩ
		V_{GS} = -10 V; I_D = -9.2 A; T_j = 150 °C; see Figure 9	-	25	31	mΩ
		V_{GS} = -4.5 V; I_D = -6.8 A; T_j = 25 °C; see Figure 10; see Figure 9	-	26	35	mΩ
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	I_D = -9.2 A; V_{DS} = -15 V; V_{GS} = -10 V; T_j = 25 °C; see Figure 11; see Figure 12	-	42	-	nC
Q_{GS}	gate-source charge		-	8	-	nC
Q_{GD}	gate-drain charge		-	6	-	nC

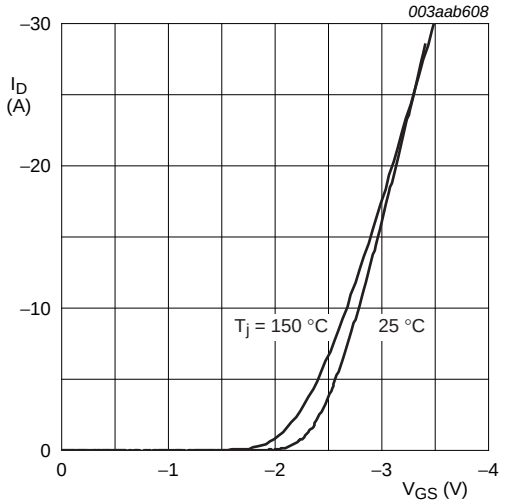
Table 6. Characteristics *...continued*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{GS(pl)}$	gate-source plateau voltage	I_D = -9.2 A; V_{DS} = -15 V; T_j = 25 °C; see Figure 11; see Figure 12	-	-2.5	-	V
C_{iss}	input capacitance	V_{DS} = -25 V; V_{GS} = 0 V; f = 1 MHz; T_j = 25 °C; see Figure 13	-	2100	-	pF
C_{oss}	output capacitance		-	365	-	pF
C_{rss}	reverse transfer capacitance		-	275	-	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = -25 V; R_L = 6 Ω; V_{GS} = -10 V; $R_{G(ext)}$ = 6 Ω; T_j = 25 °C	-	9	-	ns
t_r	rise time		-	9	-	ns
$t_{d(off)}$	turn-off delay time		-	50	-	ns
t_f	fall time		-	24	-	ns
Source-drain diode						
V_{SD}	source-drain voltage	I_S = -3.45 A; V_{GS} = 0 V; T_j = 25 °C; see Figure 14	-	-0.8	-1.2	V



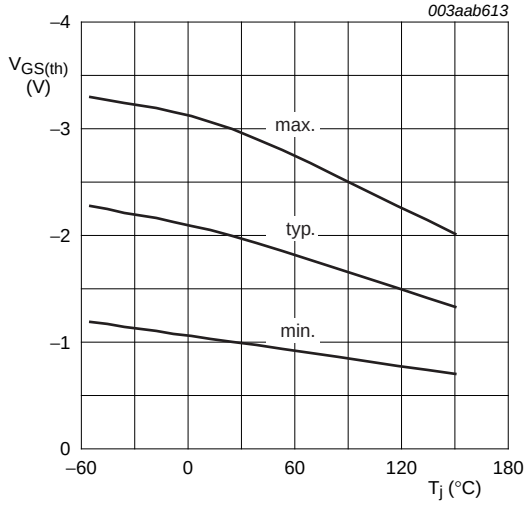
T_j = 25 °C

Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values



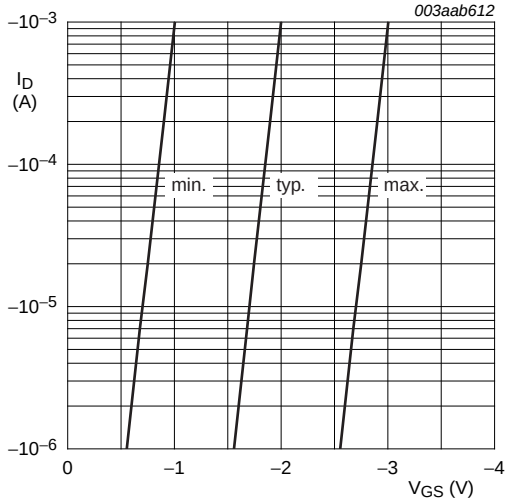
$V_{DS} > I_D \times R_{DSon}$

Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values



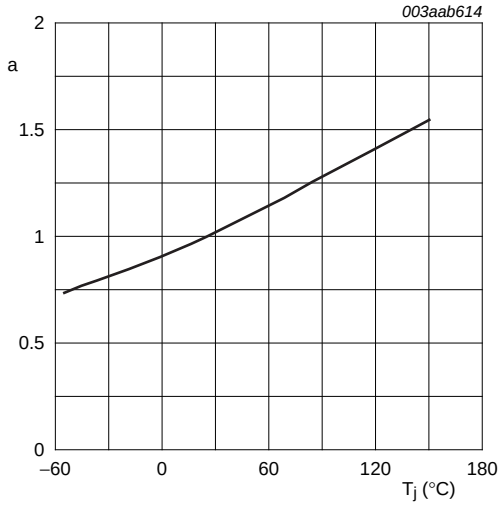
I_D = -1 mA; V_{DS} = V_{GS}

Fig 7. Gate-source threshold voltage as a function of junction temperature



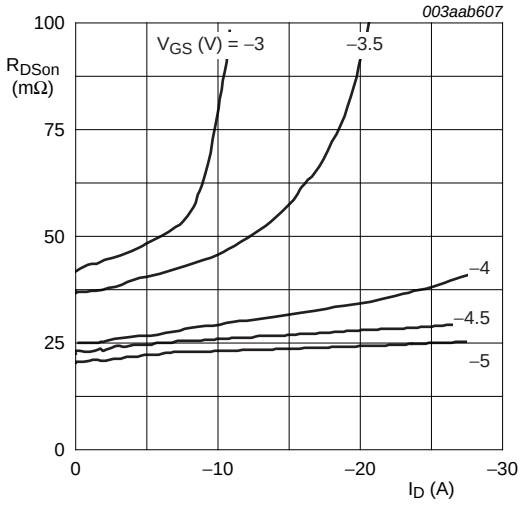
T_j = 25 °C; V_{DS} = -5 V

Fig 8. Sub-threshold drain current as a function of gate-source voltage



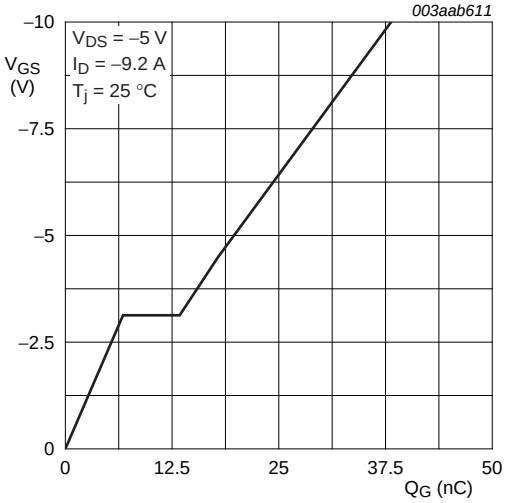
$$a = \frac{R_{DSon}}{R_{DSon(25°C)}}$$

Fig 9. Normalized drain-source on-state resistance factor as a function of junction temperature



T_j = 25 °C

Fig 10. Drain-source on-state resistance as a function of drain current; typical values



I_D = -9.2 A; V_{DS} = -15 V; T_j = 25 °C

Fig 11. Gate-source voltage as a function of gate charge; typical values

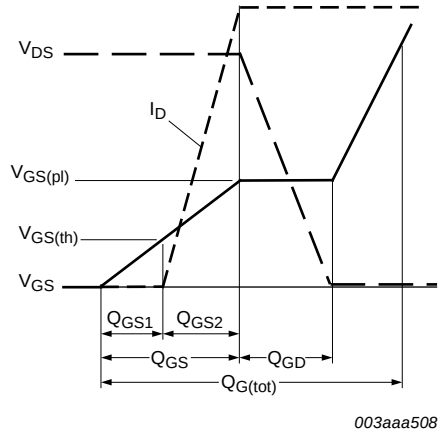
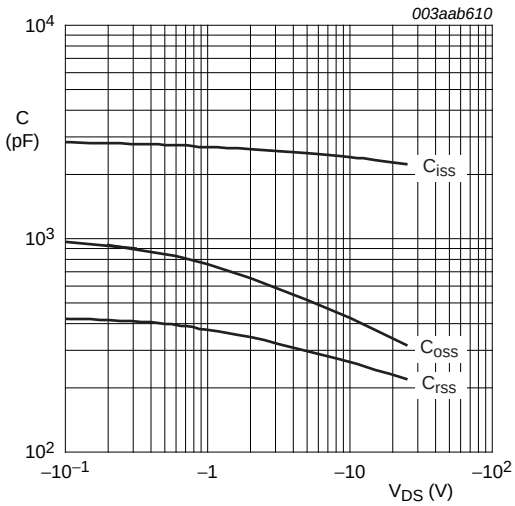
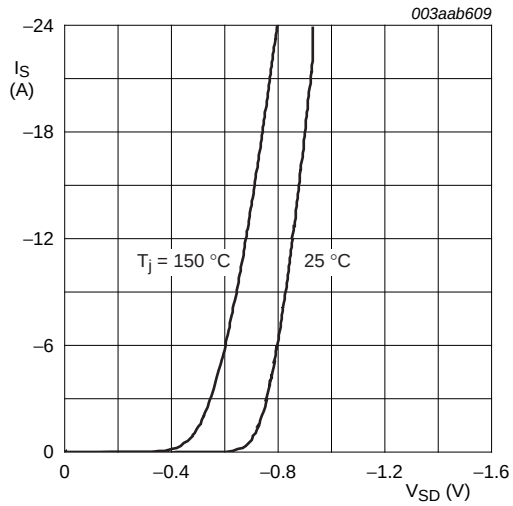


Fig 12. Gate charge waveform definitions



V_{GS} = 0 V; f = 1 MHz

Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

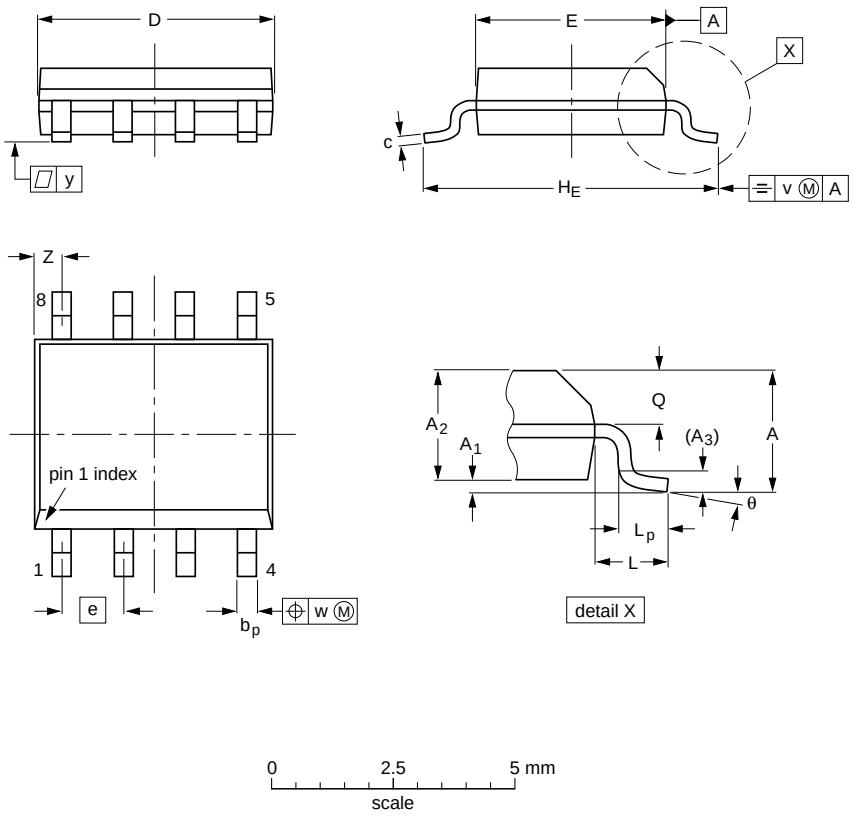


V_{GS} = 0 V

Fig 14. Source current as a function of source-drain voltage; typical values

7. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm **SOT96-1**



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(2)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8^o 0^o
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.20 0.19	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Notes

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT96-1	076E03	MS-012				~~99-12-27~~ 03-02-18

Fig 15. Package outline SOT96-1 (SO8)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMK35EP_2	20100429	Product data sheet	-	PMK35EP_1
Modifications:	• Various changes to content.			
PMK35EP_1	20070917	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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11. Contents

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